

General Description

The MAX4675/MAX4676 single analog switches feature 3Ω (max) on-resistance (R_{ON}) and 0.7Ω flatness when operating from dual ±5V supplies. These switches can handle Rail-to-Rail® analog signals. Off-leakage current is 0.1nA at $T_A = +25$ °C. The MAX4675/MAX4676 are ideal in low-distortion applications and are the preferred solution over mechanical relays in automated test equipment or applications where current switching is required. They are more reliable than mechanical relays, have low power requirements (<1µA), and are available in a space-saving 6-pin SOT23 package.

The MAX4675 has a single normally open (NO) switch, and the MAX4676 has a single normally closed (NC) switch.

The MAX4675/MAX4676 operate from either a single +2.7V to +5.5V or dual $\pm 2.7V$ to $\pm 5.5V$ supplies, making them ideal for use in digital card applications and single-ended 75 Ω systems.

Applications

Reed Relay Replacement

Test Equipment

Communications Systems

PBX, PABX Systems

Audio Signal Routing

Avionics

ADC Systems

Data-Acquisition Systems

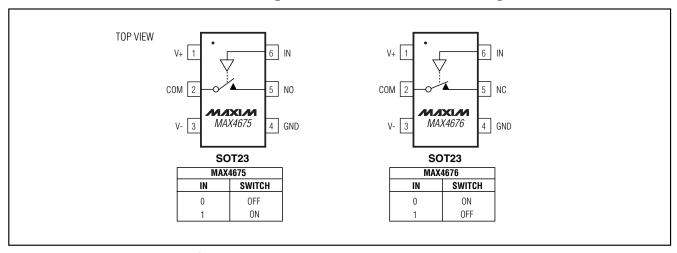
Features

- ♦ 3Ω (max) Ron
- ♦ 0.7Ω (max) Ron Flatness
- ◆ Dual ±2.7V to ±5.5V or Single +2.7V to +5.5V Supply Range
- ♦ Off-Isolation
 - -75dB at 1MHz, Dual Supply -65dB at 1MHz, Single Supply
- ◆ -3dB Bandwidth 250MHz
- ♦ Rail-to-Rail Signal Handling

Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	SOT MARK	
MAX4675EUT-T	-40°C to +85°C	6 SOT23-6	AAND	
MAX4676EUT-T	-40°C to +85°C	6 SOT23-6	AANE	

Pin Configurations/Functional Diagrams/Truth Tables



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

MIXIM

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ABSOLUTE MAXIMUM RATINGS

V+ to GND	0.3V to +6V	Continuous Power Dissipation ($T_A = +7$	′0°C)
V- to GND	+0.3V to -6V	6-Pin SOT23 (derate 8.7mW/°C abov	/e +70°C)691mW
V+ to V	12V	Operating Temperature Range	40°C to +85°C
IN to GND	0.3V to (V+ + 0.3V)	Junction Temperature	
All Other Pins (Note 1)	(V 0.3V) to $(V+ + 0.3V)$	Storage Temperature Range	65°C to +150°C
Continuous Current (NO, NC, COM)	±100mA	Lead Temperature (soldering, 10s)	+300°C
Peak Current (NO, NC, COM, pulse	d at 1ms	, , , , , , , , , , , , , , , , , , , ,	
(400/ -1	. 000 1		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current rating.

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES

 $(V+ = +5V \pm 10\%, V- = -5V \pm 10\%, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}					V+	V	
On Desistance	D.	V+ = 4.5V, V- = -4.5V, ICOM	T _A = +25°C		2.4	3	0	
On-Resistance	Ron	= 50mA; V_{NO} or V_{NC} = $\pm 3.3 V$	T _A = T _{MIN} to T _{MAX}			4	Ω	
On-Resistance Flatness	D.	V+ = 4.5V, V- = -4.5V,	T _A = +25°C		0.4	0.7	0	
(Note 4)	RFLAT	$I_{COM} = 50 \text{mA}; V_{NO} \text{ or} $ $V_{NC} = \pm 3.3 \text{V}, 0$	$T_A = T_{MIN}$ to T_{MAX}			1.0	Ω	
NC or NO Off-Leakage		V+ = 5.5V, V- = -5.5V,	T _A = +25°C	-1	0.1	1	nA	
Current	IN_(OFF)	$V_{COM} = 4.5V$; V_{NO} or $V_{NC} = \pm 4.5V$	TA = TMIN to TMAX	-10		10		
0000000		V+ = 5.5V, V- = -5.5V,	T _A = +25°C	-1	0.1	1	nA	
COM Off-Leakage Current	ICOM(OFF)	$V_{COM} = +4.5V$; V_{NO} or $V_{NC} = \pm4.5V$,	-10		10		
COM On-Leakage Current	loon(on)	V+ = 5.5V, V- = -5.5V,	T _A = +25°C	-2	0.1	2	n /	
	ICOM(ON)	$V_{COM} = \pm 4.5V$; V_{NO} or V_{NC} = $\pm 4.5V$ or floating $T_A = T_{MIN}$ to T_{MAX}	$T_A = T_{MIN}$ to T_{MAX}	-20		20	- nA	
LOGIC INPUT								
Input Low Voltage	V _{IL}					0.8	V	
Input High Voltage	VIH			2.4			V	
Input Leakage Current	I _{IN}			-1	0.005	1	μΑ	
DYNAMIC	DYNAMIC							
		V+ = +4.5V, V- = -4.5V;	T _A = +25°C		135	300		
Turn-On Time	ton	V_{NO} or $V_{NC} = 3.3V$, $R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			375	ns	
T 0# Time		V+ = +4.5V, V- = -4.5V;	T _A = +25°C		50	110		
Turn-Off Time	toff	V_{NO} or $V_{NC} = 3.3V$, $R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			125	ns	

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES (continued)

 $(V+ = +5V \pm 10\%, V- = -5V \pm 10\%, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIO	NS	MIN	TYP	MAX	UNITS
Charge Injection	Q	$R_{GEN} = 0\Omega$, $C_L = 1nF$, $V_{GEN} = 0$, Figure 3	T _A = +25°C		87		рС
Off-Isolation	V _{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4	T _A = +25°C		-75		dB
On-Channel Bandwidth (-3dB)	BW	$R_S = 50\Omega$, $R_L = 50\Omega$			250		MHz
NC or NO Off-Capacitance	C _(N_OFF)	f = 1MHz, Figure 5	T _A = +25°C		85		рF
COM Off-Capacitance	C(COMOFF)	f = 1MHz, Figure 5	T _A = +25°C		85		рF
On-Capacitance	C _(ON)	f = 1MHz, Figure 5	T _A = +25°C		350		рF
POWER SUPPLY							
Supply Voltage	V+, V-			±2.7		±5.5	V
Positive Supply Current	l+	V _{IN} = 0 or 5.5V, V+ =	T _A = +25°C		0.002	1	^
		5.5V, V- = -5.5V	$T_A = T_{MIN}$ to T_{MAX}			10	μΑ
Negative Supply Current	-	$V_{IN} = 0 \text{ or } 5.5V,$	T _A = +25°C	-1	-0.002		μА
		V+ = 5.5V, V- = -5.5V	$T_A = T_{MIN}$ to T_{MAX}	-10			<u> </u>

ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY

 $(V+ = +5V \pm 10\%, V- = 0, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25$ °C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On Desigtance	D	$V+ = 4.5V; I_{COM} = 50mA;$	T _A = +25°C		3.5	5.75	0
On-Resistance	R _{ON}	V_{NO} or $V_{NC} = 3.3V$	$T_A = T_{MIN}$ to T_{MAX}			7.5	Ω
On-Resistance Flatness	R _{FLAT}	V+ = 4.5V; I _{COM} = 50mA; V _{NO} or V _{NC} = 1.5V, 2.5V, 3.3V	T _A = +25°C		0.4	1.6	0
(Note 4)			TA = TMIN to TMAX			2	Ω
NC or NO Off-Leakage		V+ = 5.5V; V _{NO} or V _{NC} = 4.5V or 0; V _{COM} = 0 or 4.5V	T _A = +25°C	-1	0.1	1	A
Current	IN_(OFF)		$T_A = T_{MIN}$ to T_{MAX}	-10		10	- nA
COM Off-Leakage Current	1	$V + = 5.5V$; V_{NO} or	T _A = +25°C	-1	0.1	1	A
	ICOM(OFF)	$V_{NC} = 4.5V \text{ or } 0;$ $V_{COM} = 0 \text{ or } 4.5V$	TA = TMIN to TMAX	-10		10	nA

ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY (continued)

 $(V+ = +5V \pm 10\%, V- = 0, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25$ °C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
COM On-Leakage Current	loon (on)	V+ = 5.5V; V _{NO} or V _{NC} = 0, 4.5V,	T _A = +25°C	-2	0.2	2	nA	
	ICOM (ON)	or floating; VCOM = 0 or 4.5V	$T_A = T_{MIN}$ to T_{MAX}	-20		20	I IIA	
LOGIC INPUT								
Input Low Voltage	VIL					0.8	V	
Input High Voltage	V _{IH}			2.4			V	
Input Leakage Current	I _{IN}			-1	0.005	1	μΑ	
DYNAMIC								
		V+ = +4.5V; V_{NO} or $V_{NC} = +3.3V,$	T _A = +25°C		350	700		
Turn-On Time	ton	$R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			850	ns	
		V+ = +4.5V; V _{NO} or V _{NC} =	T _A = +25°C		55	150	ns	
Turn-Off Time	toff +	$+3.3V$, R _L = 300Ω , C _L = $35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			160		
Charge Injection	Q	$R_{GEN} = 0\Omega$, $C_L = 1nF$, $V_{GEN} = 2.5V$, Figure 3	T _A = +25°C		31		рС	
Off-Isolation	V _{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4	T _A = +25°C		-65		dB	
On-Channel Bandwidth (-3dB)		$R_S = 50\Omega$, $R_L = 50\Omega$			150		MHz	
NC or NO Off-Capacitance	C _(N_OFF)	f = 1MHz, Figure 5	T _A = +25°C		85		pF	
COM Off-Capacitance	C(COMOFF)	f = 1MHz, Figure 5	T _A = +25°C		85		pF	
On-Capacitance	C _(ON)	f = 1MHz, Figure 5	T _A = +25°C		350		рF	
POWER SUPPLY								
Supply Voltage	V+			2.7		5.5	V	
B 111 0 1 0 1		$V_{IN} = 0$ or $5V$,	T _A = +25°C		0.002	1		
Positive Supply Current	l+	V+ = 5.5V	$T_A = T_{MIN}$ to T_{MAX}			10	μA	

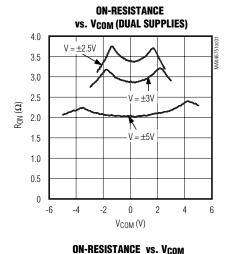
Note 2: Parameters are 100% tested at +25°C only and guaranteed by correlation through the full-rated temperature range.

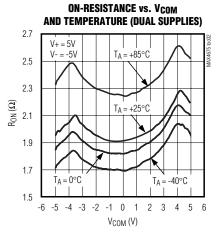
Note 3: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

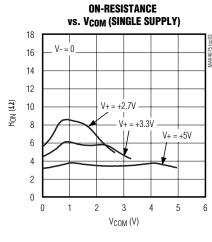
Note 4: Flatness is defined as the difference between the maximum and minimum value of R_{ON} as measured over the specified analog signal ranges.

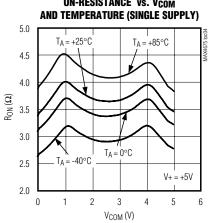
Typical Operating Characteristics

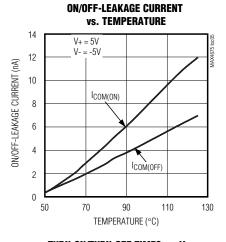
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

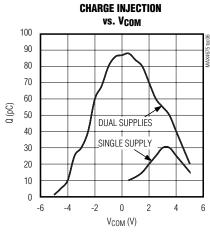


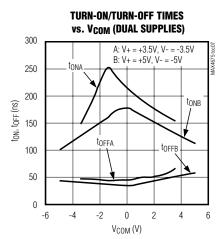


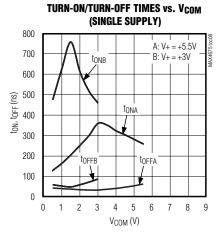


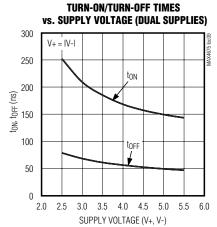






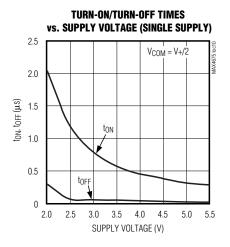


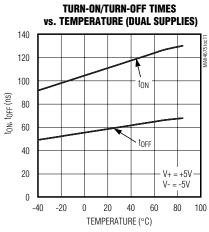


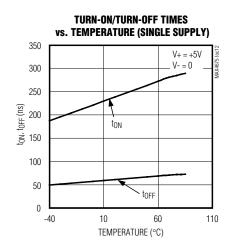


Typical Operating Characteristics (continued)

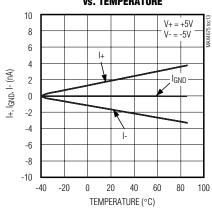
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



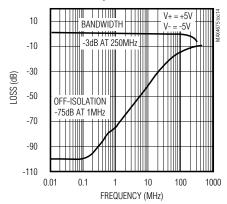




POWER-SUPPLY CURRENT vs. TEMPERATURE



FREQUENCY RESPONSE



Pin Description

	PIN		FUNCTION		
MAX4675	MAX4676	NAME	FONCTION		
1	1	V+	Positive Supply		
2	2	COM	Analog Switch Common Terminals		
3	3	V-	Negative Supply		
4	4	GND	Ground		
5	_	NO	Analog Switch Normally Open Terminal		
_	5	NC	Analog Switch Normally Closed Terminal		
6	6	IN	Logic Input		

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, NC, or COM. If proper power-supply sequencing is not possible, add two small-signal diodes (D1, D2) in series with the supply pins (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V- but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 12V.

Power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A 0.1µF capacitor connected from V+ to GND is adequate for most applications.

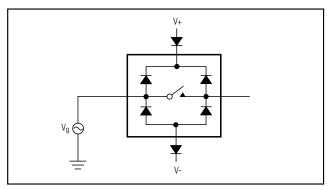


Figure 1. Overvoltage Protection Using External Blocking Diodes

Timing Diagrams/Test Circuits

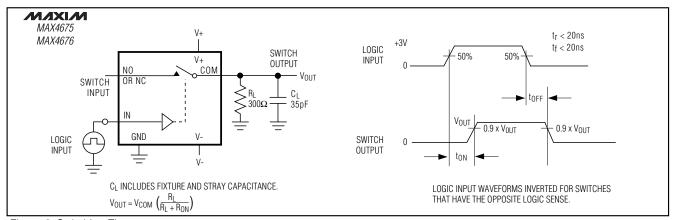


Figure 2. Switching Time

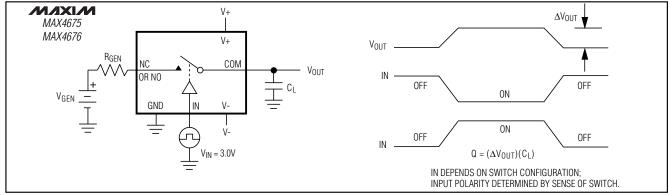


Figure 3. Charge Injection

Timing Diagrams/Test Circuits (continued)

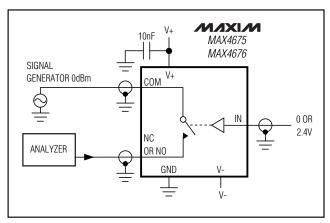


Figure 4. Off-Isolation/On-Channel Bandwidth

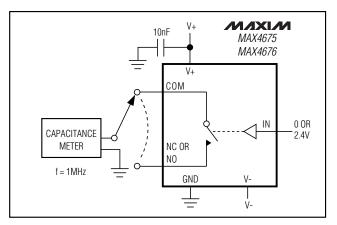
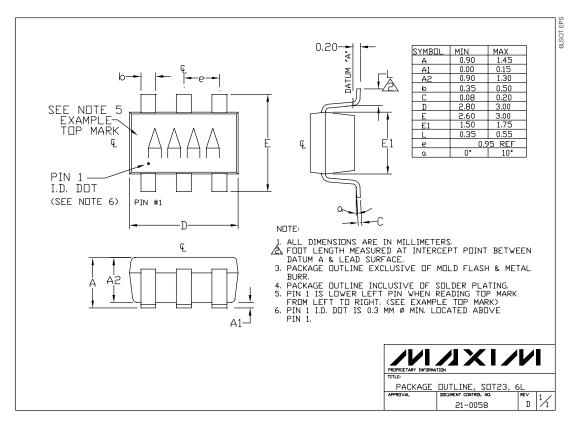


Figure 5. Channel On/Off-Capacitance

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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